

Feature

- High Precision GaAs process
- High performance, shielded
- GaAs substrate, 50Ω CPW output
- Au wire bonding, for MCM applications

Environmental Specifications

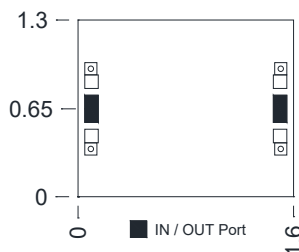
| | |
|-----------------------|--------------|
| Operating Temperature | -55°C~+85°C |
| Storage Temperature | -65°C~+150°C |
| Max. Input Power | 30dBm |

Electrical Specifications(T_A=+25°C)

| Parameter | Min. | Typ. | Max. | Unit |
|---------------------------------|-------------|-------|------|------|
| Center Freq. (f ₀) | - | 27.25 | - | GHz |
| Pass band | 26 | - | 28.5 | GHz |
| Insertion Loss @ f ₀ | - | - | 2.8 | dB |
| Ripple in Pass band | - | - | 1 | dB |
| Return Loss | 10 | - | - | dB |
| Out of band Attenuation | ≥40@23.5GHz | | | dB |
| | ≥30@30.8GHz | | | dB |

S2P file name: BWBF-26_28R5.s2p

Outline Drawing

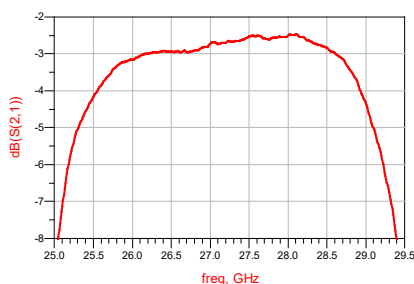


Notes:

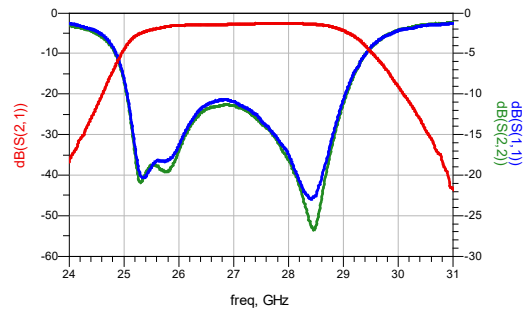
1. Dimensions are in millimeters. Tolerance: ±0.05mm
2. Die thickness is 0.1mm
3. Typical bond pad is 0.1x0.1 mm².
4. The bottom of the device is gold plated, should be grounded.

Typical Test Curves

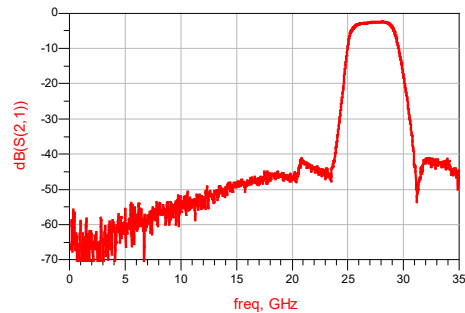
Insertion Loss VS Frequency (T_A=25°C)



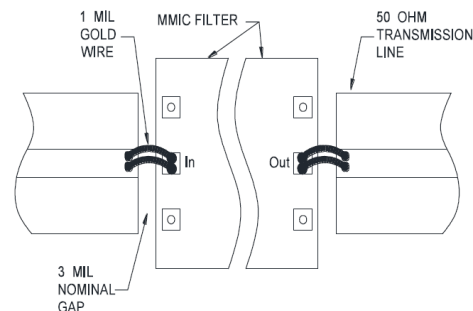
Insertion Loss & Return Loss VS Frequency (T_A=25°C)



Broadband Insertion Loss VS Frequency (T_A=25°C)



Recommended Assembly Diagrams



Application Notes:

1. The chip is back-metallized and can be die-mounted with AuSn eutectic preforms or with electrically conductive epoxy.
2. The die should be assembled on carriers like Kovar or Mu-Cu which have same Coefficient of thermal expansion. (5.8×10⁻⁶/) with GaAs.
3. Recommend using Φ25um Au wire for bonding, whose length is around 400um.
4. Sinter by AuSn (80/20), which doesn't exceed 300°C within 30 seconds max.
4. Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.
5. Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers.
6. The device is sensitive to ESD. ESD protection is required during storage and usage.
7. If you have any questions, please contact us.